

FEATURES

High speed

850 MHz, -3 dB bandwidth ($G = +1$, $R_L = 1$ k Ω , LFCSP)

750 MHz, -3 dB bandwidth ($G = +1$, $R_L = 1$ k Ω , SOIC)

2800 V/ μ s slew rate

Low distortion: -88 dBc @ 10 MHz ($G = +1$, $R_L = 1$ k Ω)

Low power: 5 mA/amplifier @ 10 V

Low noise: 4.4 nV/ $\sqrt{\text{Hz}}$

Wide supply voltage range: 5 V to 10 V

Power-down feature

Available in 3 mm $\times$ 3 mm 8-lead LFCSP (single), 8-lead SOIC (single), and 4 mm $\times$ 4 mm 16-lead LFCSP (dual)

APPLICATIONS

Instrumentation

IF and baseband amplifiers

Active filters

ADC drivers

DAC buffers

CONNECTION DIAGRAMS

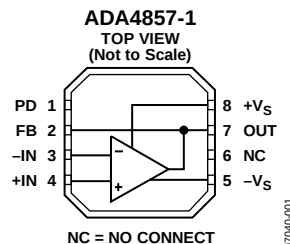


Figure 1. 8-Lead LFCSP (CP)

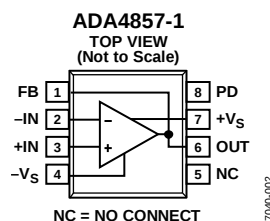


Figure 2. 8-Lead SOIC (R)

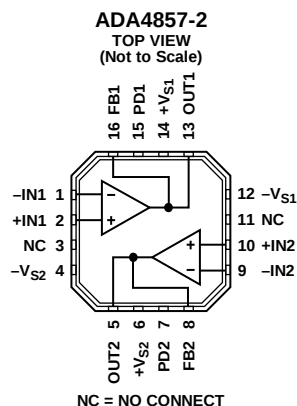


Figure 3. 16-Lead LFCSP (CP)

GENERAL DESCRIPTION

The ADA4857 is a unity-gain stable, high speed, voltage feedback amplifier with low distortion, low noise, and high slew rate. With a spurious-free dynamic range (SFDR) of -88 dBc @ 10 MHz, the ADA4857 is an ideal solution for a variety of applications, including ultrasounds, ATE, active filters, and ADC drivers. The Analog Devices, Inc., proprietary next-generation XFCB process and innovative architecture enables such high performance amplifiers.

The ADA4857 has 850 MHz bandwidth, 2800 V/ μ s slew rate, and settles to 0.1% in 15 ns. With a wide supply voltage range (5 V to 10 V), the ADA4857 is an ideal candidate for systems that require high dynamic range, precision, and speed.

The ADA4857-1 amplifier is available in a 3 mm $\times$ 3 mm, 8-lead LFCSP and a standard 8-lead SOIC. The ADA4857-2 is available in a 4 mm $\times$ 4 mm, 16-lead LFCSP. The LFCSP features an exposed paddle that provides a low thermal resistance path to the printed circuit board (PCB). This path enables more efficient heat transfer and increases reliability. The ADA4857 works over the extended industrial temperature range (-40°C to $+125^{\circ}\text{C}$).

Rev. B

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

TABLE OF CONTENTS

Features	1	Test Circuits.....	15
Applications.....	1	Applications Information	16
Connection Diagrams.....	1	Power-Down Operation	16
General Description	1	Capacitive Load Considerations	16
Revision History	2	Recommended Values for Various Gains.....	16
Specifications.....	3	Active Low-Pass Filter (LPF)	17
± 5 V Supply	3	Noise	18
+5 V Supply	4	Circuit Considerations	18
Absolute Maximum Ratings.....	6	PCB Layout	18
Thermal Resistance	6	Power Supply Bypassing.....	18
Maximum Power Dissipation	6	Grounding	18
ESD Caution.....	6	Outline Dimensions	19
Pin Configurations and Function Descriptions	7	Ordering Guide	20
Typical Performance Characteristics	9		

REVISION HISTORY

8/11—Rev. A to Rev. B

Changes to Table 1 Conditions	3
Changes to Table 2 Conditions	4
Changes to Typical Performance Characteristics Conditions	9
Changes to Figure 18.....	10
Changes to Figure 42.....	15
Changes to Table 9.....	16
Changes to Ordering Guide	20

11/08—Rev. 0 to Rev. A

Changes to Table 5.....	7
Changes to Table 7.....	8
Changes to Figure 32.....	13
Added Figure 44; Renumbered Sequentially	15
Changes to Layout	15
Changes to Table 8.....	16
Added Active Low-Pass Filter (LFP) Section.....	17
Added Figure 48 and Figure 49; Renumbered Sequentially	17
Changes to Grounding Section.....	18
Exposed Paddle Notation Added to Outline Dimensions	19
Changes to Ordering Guide	20

5/08—Revision 0: Initial Version

SPECIFICATIONS

±5 V SUPPLY

$T_A = 25^\circ\text{C}$, $G = +2$, $R_G = R_F = 499\ \Omega$, $R_S = 100\ \Omega$ for $G = +1$ (SOIC), $R_L = 1\ \text{k}\Omega$ to ground, PD = no connect, unless otherwise noted.

Table 1.

Parameter	Conditions	Min	Typ	Max	Unit	
DYNAMIC PERFORMANCE						
–3 dB Bandwidth (LFCSP/SOIC)	G = +1, V _{OUT} = 0.2 V p-p	650	850/750		MHz	
	G = +1, V _{OUT} = 2 V p-p		600/550		MHz	
	G = +2, V _{OUT} = 0.2 V p-p		400/350		MHz	
	Full Power Bandwidth		110		MHz	
	Bandwidth for 0.1 dB Flatness (LFCSP/SOIC)	G = +2, V _{OUT} = 2 V p-p, R _L = 150 Ω		75/90		MHz
	Slew Rate (10% to 90%)	G = +1, V _{OUT} = 4 V step		2800		V/μs
	Settling Time to 0.1%	G = +2, V _{OUT} = 2 V step		15		ns
NOISE/HARMONIC PERFORMANCE						
Harmonic Distortion	f = 1 MHz, G = +1, V _{OUT} = 2 V p-p (HD2)		–108		dBc	
	f = 1 MHz, G = +1, V _{OUT} = 2 V p-p (HD3)		–108		dBc	
	f = 10 MHz, G = +1, V _{OUT} = 2 V p-p (HD2)		–88		dBc	
	f = 10 MHz, G = +1, V _{OUT} = 2 V p-p (HD3)		–93		dBc	
	f = 50 MHz, G = +1, V _{OUT} = 2 V p-p (HD2)		–65		dBc	
	f = 50 MHz, G = +1, V _{OUT} = 2 V p-p (HD3)		–62		dBc	
	Input Voltage Noise	f = 100 kHz		4.4		nV/√Hz
Input Current Noise	f = 100 kHz		1.5		pA/√Hz	
DC PERFORMANCE						
Input Offset Voltage	V _{OUT} = –2.5 V to +2.5 V		±2	±4.5	mV	
Input Offset Voltage Drift			2.3		μV/°C	
Input Bias Current			–2	–3.3	μA	
Input Bias Current Drift			24.5		nA/°C	
Input Bias Offset Current			50		nA	
Open-Loop Gain			57		dB	
PD (POWER-DOWN) PIN						
PD Input Voltage	Chip powered down		≥(V _{CC} – 2)		V	
	Chip enabled		≤(V _{CC} – 4.2)		V	
Turn-Off Time	50% off PD to <10% of final V _{OUT} , V _{IN} = 1 V, G = +2		55		μs	
Turn-On Time	50% off PD to <10% of final V _{OUT} , V _{IN} = 1 V, G = +2		33		ns	
PD Pin Leakage Current	Chip enabled		58		μA	
	Chip powered down		80		μA	
INPUT CHARACTERISTICS						
Input Resistance	Common mode		8		MΩ	
	Differential mode		4		MΩ	
Input Capacitance	Common mode		2		pF	
Input Common-Mode Voltage Range			±4		V	
Common-Mode Rejection Ratio	V _{CM} = ±1 V	–78	–86		dB	
OUTPUT CHARACTERISTICS						
Output Overdrive Recovery Time	V _{IN} = ±2.5 V, G = +2		10		ns	
Output Voltage Swing	R _L = 1 kΩ		±4		V	
	R _L = 100 Ω		±3.7		V	
Output Current			50		mA	
Short-Circuit Current	Sinking and sourcing		125		mA	
Capacitive Load Drive	30% overshoot, G = +2		10		pF	

Parameter	Conditions	Min	Typ	Max	Unit
POWER SUPPLY					
Operating Range		4.5		10.5	V
Quiescent Current			5	5.5	mA
Quiescent Current (Power Down)	$PD \geq V_{CC} - 2\text{ V}$		350	450	μA
Positive Power Supply Rejection	$+V_S = 4.5\text{ V to } 5.5\text{ V}, -V_S = -5\text{ V}$	-59	-62		dB
Negative Power Supply Rejection	$+V_S = 5\text{ V}, -V_S = -4.5\text{ V to } -5.5\text{ V}$	-65	-68		dB

+5 V SUPPLY

$T_A = 25^\circ\text{C}$, $G = +2$, $R_F = R_G = 499\ \Omega$, $R_S = 100\ \Omega$ for $G = +1$ (SOIC), $R_L = 1\text{ k}\Omega$ to midsupply, $PD = \text{no connect}$, unless otherwise noted.

Table 2.

Parameter	Conditions	Min	Typ	Max	Unit
DYNAMIC PERFORMANCE					
-3 dB Bandwidth (LFCSP/SOIC)	$G = +1, V_{OUT} = 0.2\text{ V p-p}$	595	800/750		MHz
	$G = +1, V_{OUT} = 2\text{ V p-p}$		500/400		MHz
	$G = +2, V_{OUT} = 0.2\text{ V p-p}$		360/300		MHz
Full Power Bandwidth	$G = +1, V_{OUT} = 2\text{ V p-p}, THD < -40\text{ dBc}$		95		MHz
Bandwidth for 0.1 dB Flatness (LFCSP/SOIC)	$G = +2, V_{OUT} = 2\text{ V p-p}, R_L = 150\ \Omega$		50/40		MHz
Slew Rate (10% to 90%)	$G = +1, V_{OUT} = 2\text{ V step}$		1500		$\text{V}/\mu\text{s}$
Settling Time to 0.1%	$G = +2, V_{OUT} = 2\text{ V step}$		15		ns
NOISE/HARMONIC PERFORMANCE					
Harmonic Distortion	$f = 1\text{ MHz}, G = +1, V_{OUT} = 2\text{ V p-p (HD2)}$		-92		dBc
	$f = 1\text{ MHz}, G = +1, V_{OUT} = 2\text{ V p-p (HD3)}$		-90		dBc
	$f = 10\text{ MHz}, G = +1, V_{OUT} = 2\text{ V p-p (HD2)}$		-81		dBc
	$f = 10\text{ MHz}, G = +1, V_{OUT} = 2\text{ V p-p (HD3)}$		-71		dBc
	$f = 50\text{ MHz}, G = +1, V_{OUT} = 2\text{ V p-p (HD2)}$		-69		dBc
	$f = 50\text{ MHz}, G = +1, V_{OUT} = 2\text{ V p-p (HD3)}$		-55		dBc
Input Voltage Noise	$f = 100\text{ kHz}$		4.4		$\text{nV}/\sqrt{\text{Hz}}$
Input Current Noise	$f = 100\text{ kHz}$		1.5		$\text{pA}/\sqrt{\text{Hz}}$
DC PERFORMANCE					
Input Offset Voltage			± 1	± 4.2	mV
Input Offset Voltage Drift			4.6		$\mu\text{V}/^\circ\text{C}$
Input Bias Current			-1.7	-3.3	μA
Input Bias Current Drift			24.5		$\text{nA}/^\circ\text{C}$
Input Bias Offset Current			50		nA
Open-Loop Gain	$V_{OUT} = 1.25\text{ V to } 3.75\text{ V}$		57		dB
PD (POWER-DOWN) PIN					
PD Input Voltage	Chip powered down		$\geq (V_{CC} - 2)$		V
	Chip enabled		$\leq (V_{CC} - 4.2)$		V
Turn-Off Time	50% off PD to <10% of final V_{OUT} , $V_{IN} = 1\text{ V}, G = +2$		38		μs
Turn-On Time	50% off PD to <10% of final V_{OUT} , $V_{IN} = 1\text{ V}, G = +2$		30		ns
PD Pin Leakage Current	Chip enable		8		μA
	Chip powered down		30		μA
INPUT CHARACTERISTICS					
Input Resistance	Common mode		8		$\text{M}\Omega$
	Differential mode		4		$\text{M}\Omega$
Input Capacitance	Common mode		2		pF
Input Common-Mode Voltage Range			1 to 4		V
Common-Mode Rejection Ratio	$V_{CM} = 2\text{ V to } 3\text{ V}$	-76	-84		dB

Parameter	Conditions	Min	Typ	Max	Unit
OUTPUT CHARACTERISTICS					
Overdrive Recovery Time	$G = +2$		15		ns
Output Voltage Swing	$R_L = 1\text{ k}\Omega$		1 to 4		V
	$R_L = 100\ \Omega$		1.1 to 3.9		V
Output Current			50		mA
Short-Circuit Current	Sinking and sourcing		75		mA
Capacitive Load Drive	30% overshoot, $G = +2$		10		pF
POWER SUPPLY					
Operating Range		4.5		10.5	V
Quiescent Current			4.5	5	mA
Quiescent Current (Power Down)	$PD \geq V_{CC} - 2\text{ V}$		250	350	μA
Positive Power Supply Rejection	$+V_S = 4.5\text{ V to }5.5\text{ V}, -V_S = 0\text{ V}$	-58	-62		dB
Negative Power Supply Rejection	$+V_S = 5\text{ V}, -V_S = -0.5\text{ V to }+0.5\text{ V}$	-65	-68		dB

ABSOLUTE MAXIMUM RATINGS

Table 3.

Parameter	Rating
Supply Voltage	11 V
Power Dissipation	See Figure 4
Common-Mode Input Voltage	$-V_S + 0.7 \text{ V}$ to $+V_S - 0.7 \text{ V}$
Differential Input Voltage	$\pm V_S$
Exposed Paddle Voltage	$-V_S$
Storage Temperature Range	-65°C to $+125^\circ\text{C}$
Operating Temperature Range	-40°C to $+125^\circ\text{C}$
Lead Temperature (Soldering, 10 sec)	300°C
Junction Temperature	150°C

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

THERMAL RESISTANCE

θ_{JA} is specified for the worst-case conditions, that is, θ_{JA} is specified for device soldered in circuit board for surface-mount packages.

Table 4.

Package Type	θ_{JA}	θ_{JC}	Unit
8-Lead SOIC	115	15	$^\circ\text{C}/\text{W}$
8-Lead LFCSP	94.5	34.8	$^\circ\text{C}/\text{W}$
16-Lead LFCSP	68.2	19	$^\circ\text{C}/\text{W}$

MAXIMUM POWER DISSIPATION

The maximum safe power dissipation for the ADA4857 is limited by the associated rise in junction temperature (T_J) on the die. At approximately 150°C , which is the glass transition temperature, the properties of the plastic change. Even temporarily exceeding this temperature limit may change the stresses that the package exerts on the die, permanently shifting the parametric performance of the ADA4857. Exceeding a junction temperature of 175°C for an extended period can result in changes in silicon devices, potentially causing degradation or loss of functionality.

The power dissipated in the package (P_D) is the sum of the quiescent power dissipation and the power dissipated in the die due to the ADA4857 drive at the output. The quiescent power is the voltage between the supply pins (V_S) times the quiescent current (I_S).

$$P_D = \text{Quiescent Power} + (\text{Total Drive Power} - \text{Load Power})$$

$$P_D = (V_S \times I_S) + \left(\frac{V_S}{2} \times \frac{V_{OUT}}{R_L} \right) - \frac{V_{OUT}^2}{R_L}$$

RMS output voltages should be considered. If R_L is referenced to $-V_S$, as in single-supply operation, the total drive power is $V_S \times I_{OUT}$. If the rms signal levels are indeterminate, consider the worst case, when $V_{OUT} = V_S/4$ for R_L to midsupply.

$$P_D = (V_S \times I_S) + \frac{(V_S/4)^2}{R_L}$$

In single-supply operation with R_L referenced to $-V_S$, the worst case is $V_{OUT} = V_S/2$.

Airflow increases heat dissipation, effectively reducing θ_{JA} .

In addition, more metal directly in contact with the package leads and exposed paddle from metal traces, through holes, ground, and power planes reduces θ_{JA} .

Figure 4 shows the maximum power dissipation in the package vs. the ambient temperature for the SOIC and LFCSP packages on a JEDEC standard 4-layer board. θ_{JA} values are approximations.

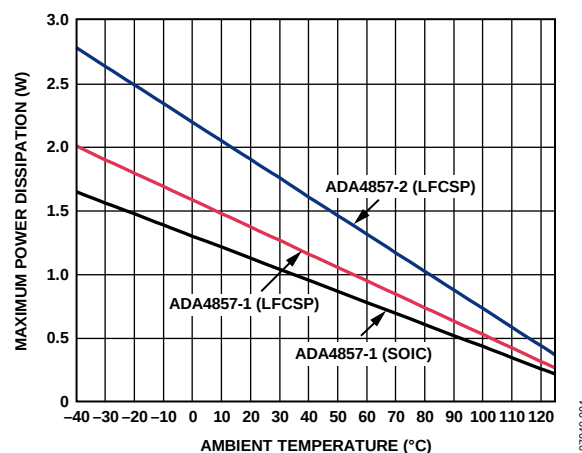


Figure 4. Maximum Power Dissipation vs. Temperature for a 4-Layer Board

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

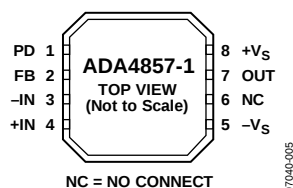


Figure 5. 8-Lead LFCSP Pin Configuration

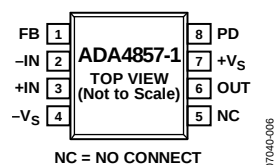


Figure 6. 8-Lead SOIC Pin Configuration

Table 5. 8-Lead LFCSP Pin Function Descriptions

Pin No.	Mnemonic	Description
1	PD	Power Down.
2	FB	Feedback.
3	-IN	Inverting Input.
4	+IN	Noninverting Input.
5	-Vs	Negative Supply.
6	NC	No Connect.
7	OUT	Output.
8	+Vs	Positive Supply.
EP	GND or Vs	Exposed Pad. The exposed pad may be connected to GND or Vs.

Table 6. 8-Lead SOIC Pin Function Descriptions

Pin No.	Mnemonic	Description
1	FB	Feedback
2	-IN	Inverting Input
3	+IN	Noninverting Input
4	-Vs	Negative Supply
5	NC	No Connect
6	OUT	Output
7	+Vs	Positive Supply
8	PD	Power Down

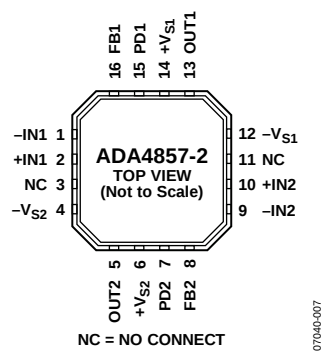


Figure 7. 16-Lead LFCSP Pin Configuration

Table 7. 16-Lead LFCSP Pin Function Descriptions

Pin No.	Mnemonic	Description
1	−IN1	Inverting Input 1.
2	+IN1	Noninverting Input 1.
3, 11	NC	No Connect.
4	−VS2	Negative Supply 2.
5	OUT2	Output 2.
6	+VS2	Positive Supply 2.
7	PD2	Power Down 2.
8	FB2	Feedback 2.
9	−IN2	Inverting Input 2.
10	+IN2	Noninverting Input 2.
12	−VS1	Negative Supply 1.
13	OUT1	Output 1.
14	+VS1	Positive Supply 1.
15	PD1	Power Down 1.
16	FB1	Feedback 1.
EP	GND or Vs	Exposed Pad. The exposed pad may be connected to GND or Vs.

TYPICAL PERFORMANCE CHARACTERISTICS

$T = 25^{\circ}\text{C}$, $G = +1$, $R_F = 0\ \Omega$, and, R_G open, $R_S = 100\ \Omega$ for SOIC, (for $G = +2$, $R_F = R_G = 499\ \Omega$), unless otherwise noted.

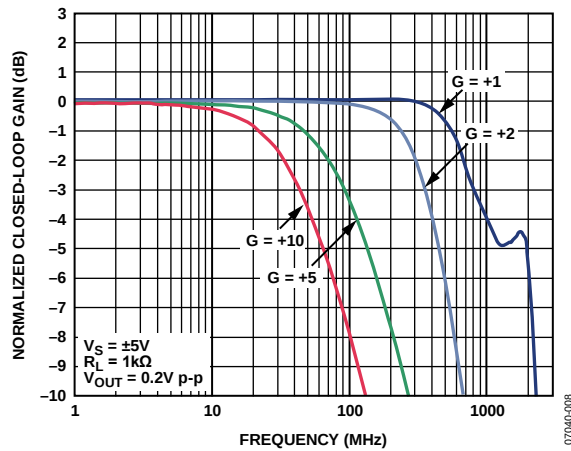


Figure 8. Small Signal Frequency Responses for Various Gains (LFCSP)

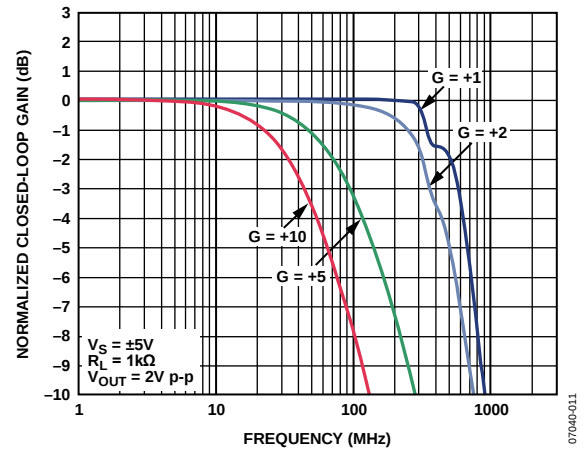


Figure 11. Large Signal Frequency Responses for Various Gains (LFCSP)

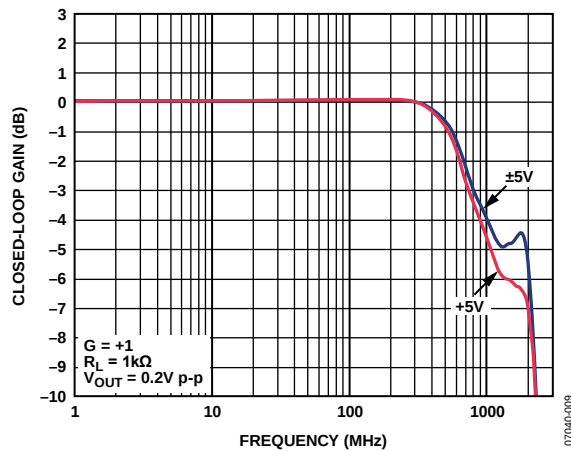


Figure 9. Small Signal Frequency Response for Various Supply Voltages (LFCSP)

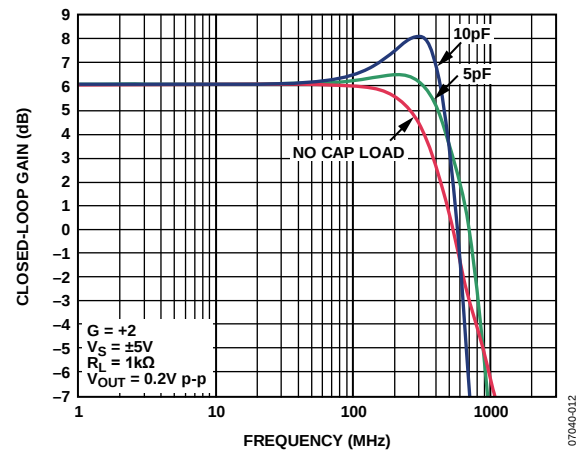


Figure 12. Small Signal Frequency Response for Various Capacitive Loads (LFCSP)

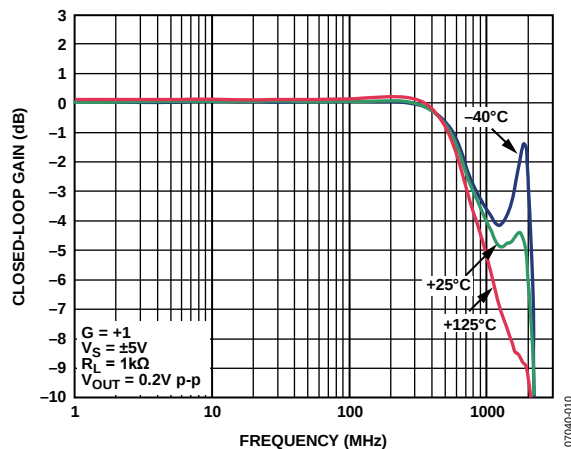


Figure 10. Small Signal Frequency Response for Various Temperatures (LFCSP)

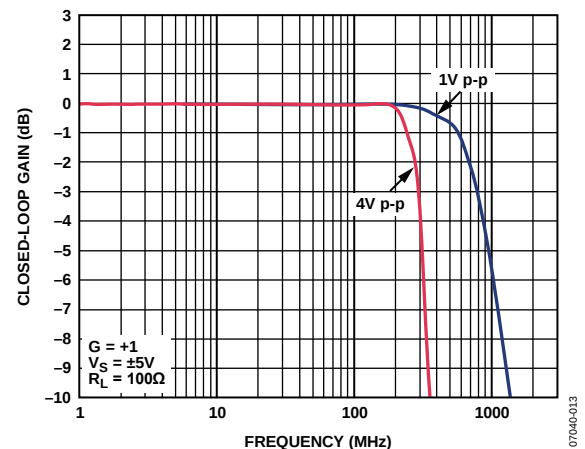


Figure 13. Large Signal Frequency Response vs. V_{OUT} (LFCSP)

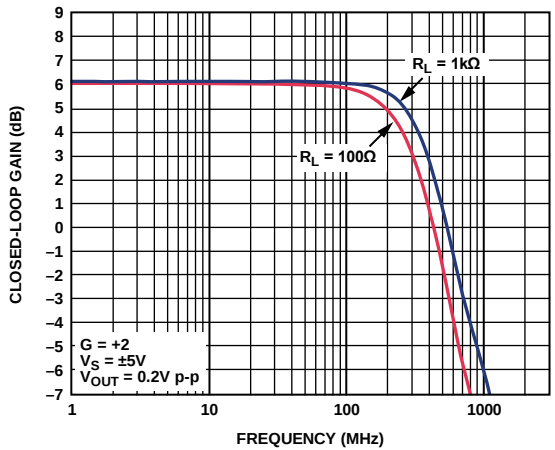


Figure 14. Small Signal Frequency Response for Various Resistive Loads (LFCSP)

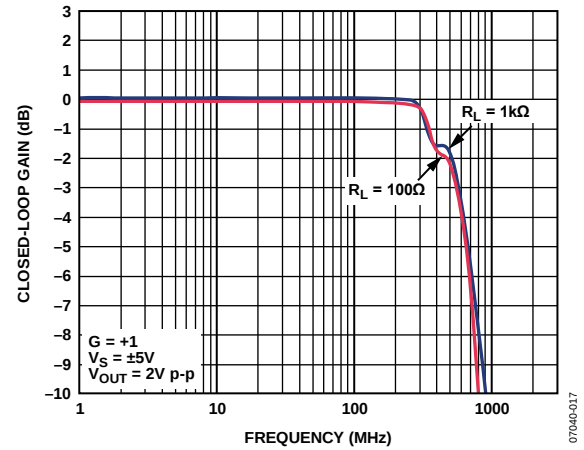


Figure 17. Large Signal Frequency Response for Various Resistive Loads (LFCSP)

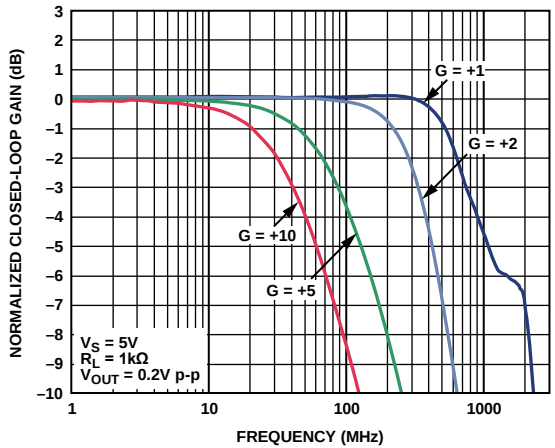


Figure 15. Small Signal Frequency Response for Various Gains (LFCSP)

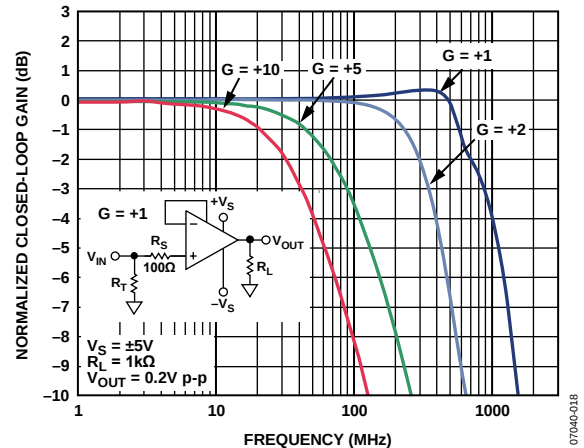


Figure 18. Small Signal Frequency Response for Various Gains (SOIC), $R_S = 100\Omega$ for $G = +1$

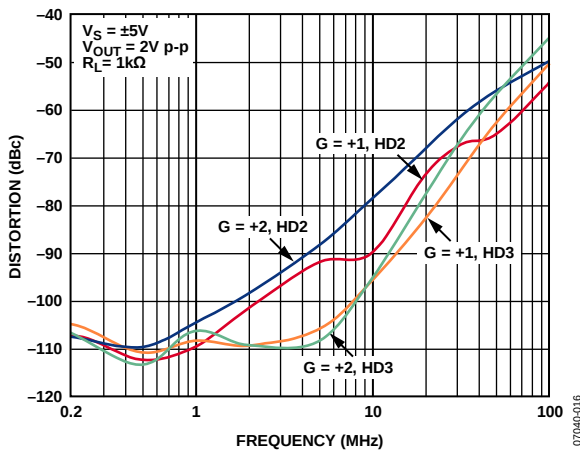


Figure 16. Harmonic Distortion vs. Frequency and Gain (LFCSP)

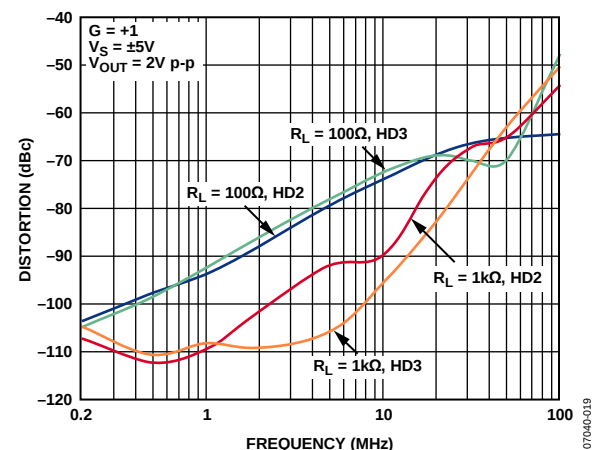


Figure 19. Harmonic Distortion vs. Frequency and Load (LFCSP)

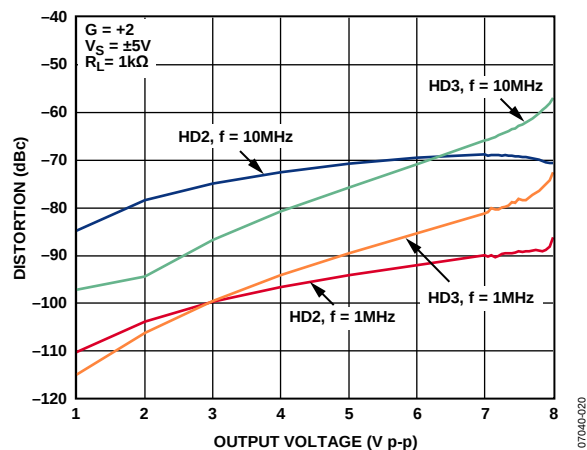


Figure 20. Harmonic Distortion vs. Output Voltage

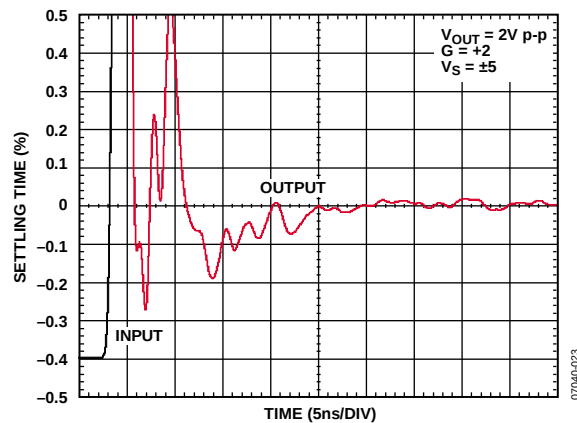


Figure 23. Short-Term Settling Time (LFCSP)

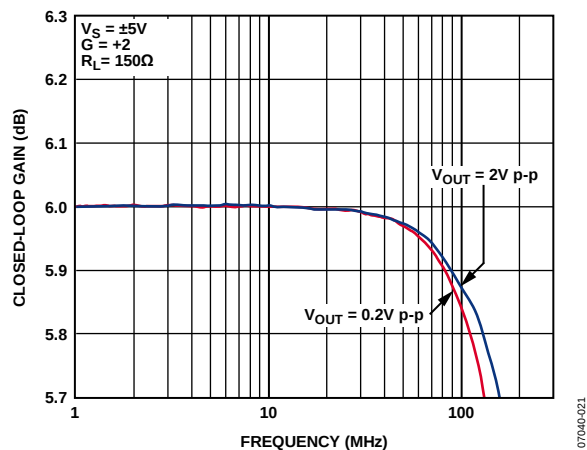


Figure 21. 0.1 dB Flatness vs. Frequency for Various Output Voltages (SOIC)

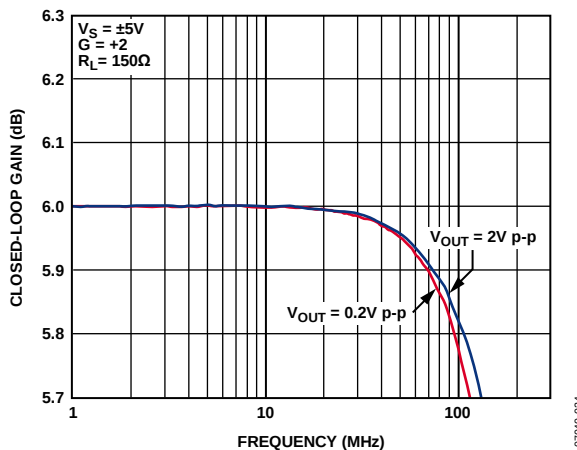


Figure 24. 0.1 dB Flatness vs. Frequency for Various Output Voltages (LFCSP)

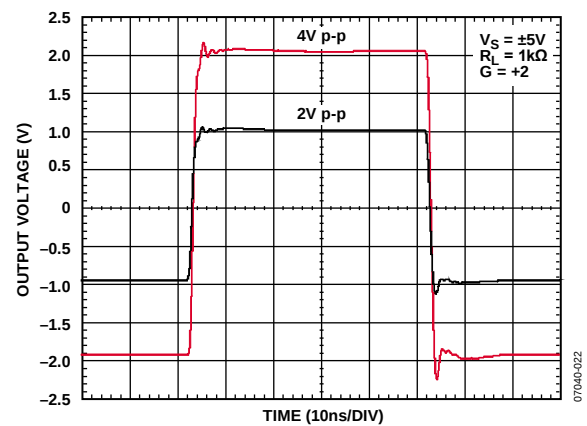


Figure 22. Large Signal Transient Response for Various Output Voltages (SOIC)

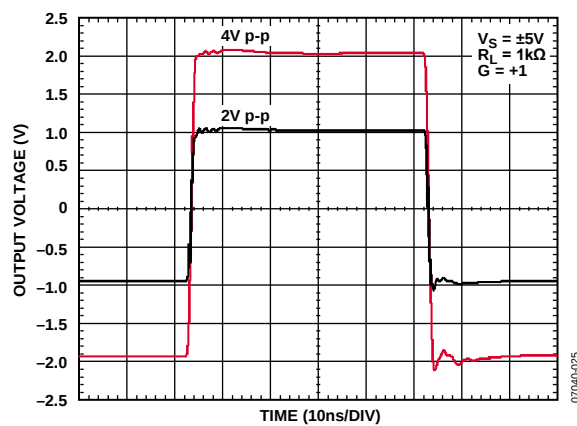


Figure 25. Large Signal Transient Response for Various Output Voltages (LFCSP)

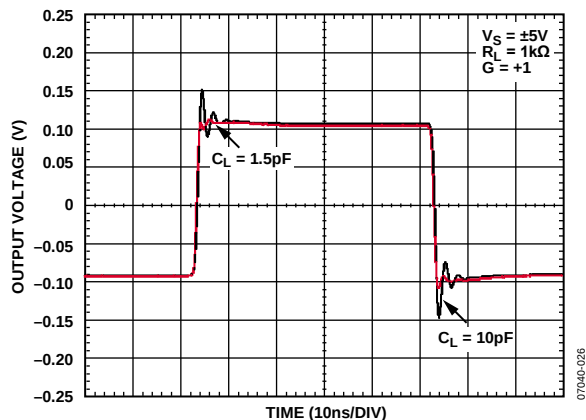


Figure 26. Small Signal Transient Response for Various Capacitive Loads (LFCSP)

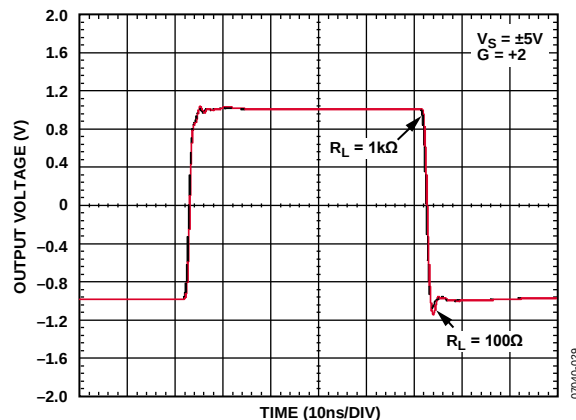


Figure 29. Large Signal Transient Response for Various Load Resistances (SOIC)

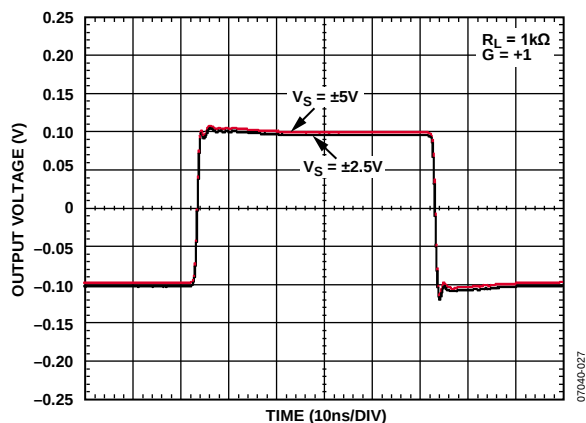


Figure 27. Small Signal Transient Response for Various Supply Voltages (LFCSP)

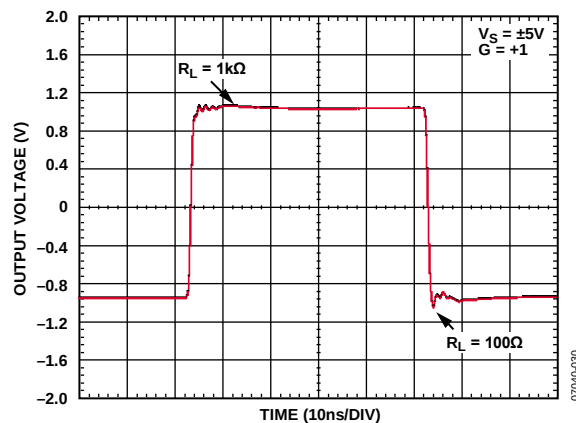


Figure 30. Large Signal Transient Response for Various Load Resistances (LFCSP)

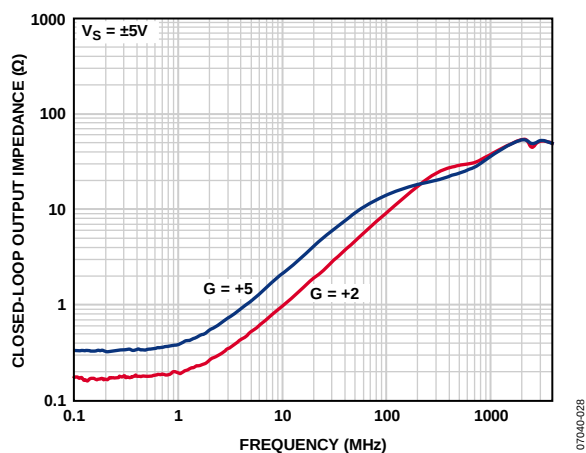


Figure 28. Closed-Loop Output Impedance vs. Frequency for Various Gains

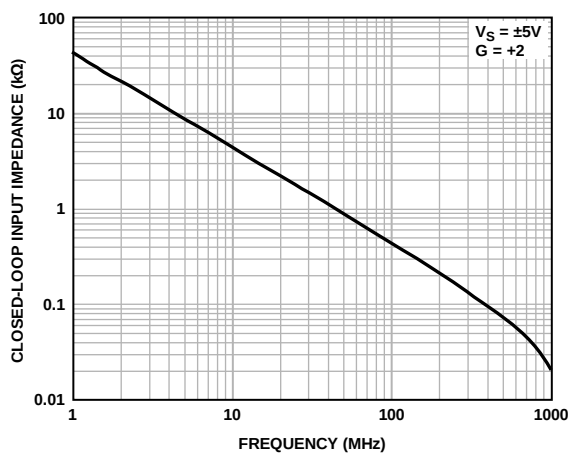


Figure 31. Closed-Loop Input Impedance vs. Frequency

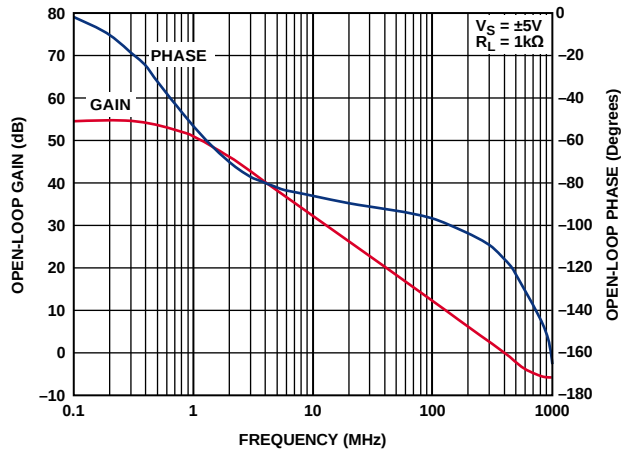


Figure 32. Open-Loop Gain and Phase vs. Frequency

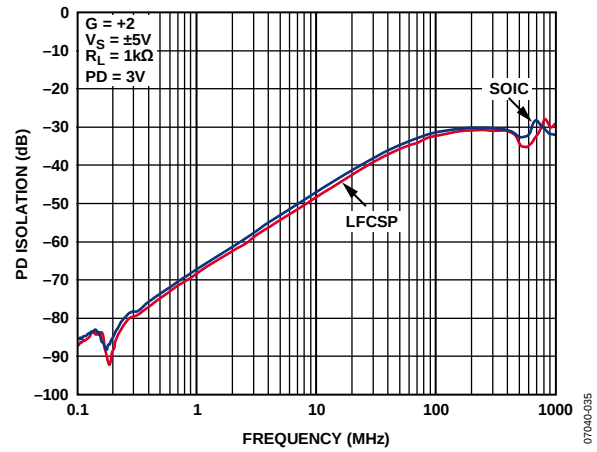


Figure 35. PD Isolation vs. Frequency

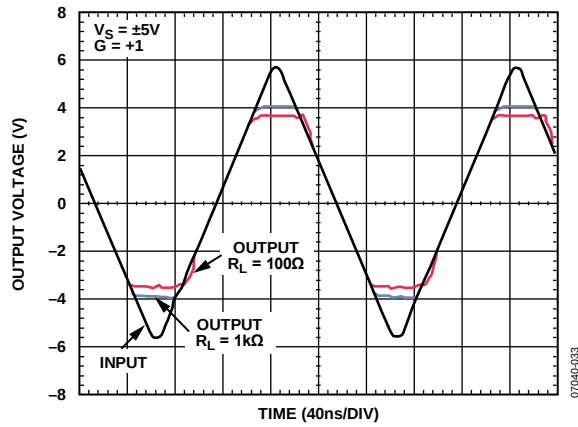


Figure 33. Input Overdrive Recovery for Various Resistive Loads

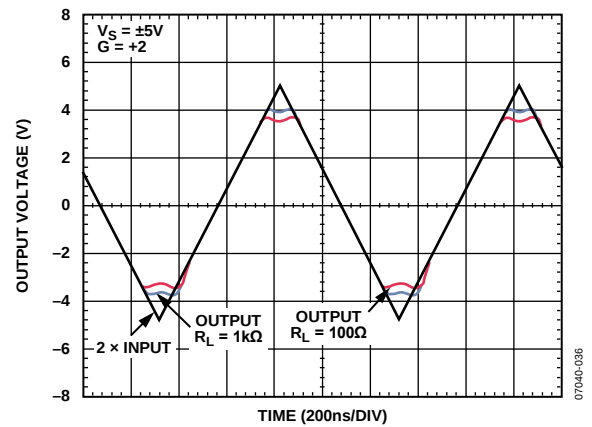


Figure 36. Output Overdrive Recovery for Various Resistive Loads

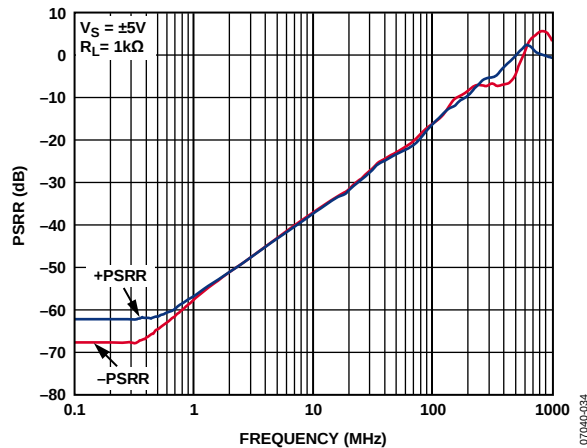


Figure 34. Power Supply Rejection Ratio (PSRR) vs. Frequency

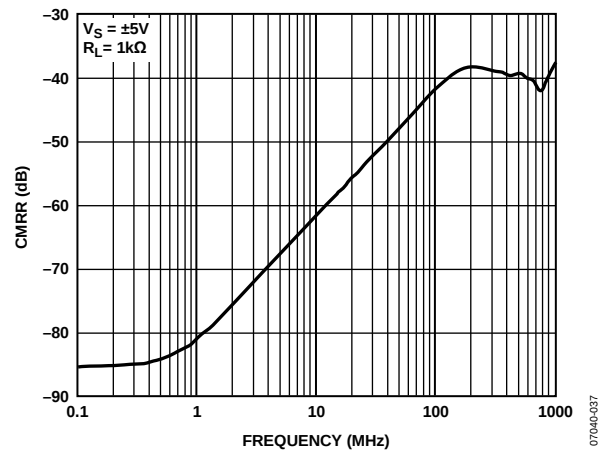


Figure 37. Common-Mode Rejection Ratio (CMRR) vs. Frequency

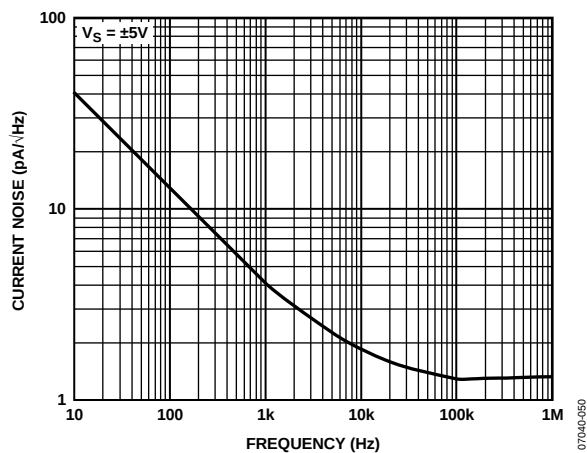


Figure 38. Input Current Noise vs. Frequency

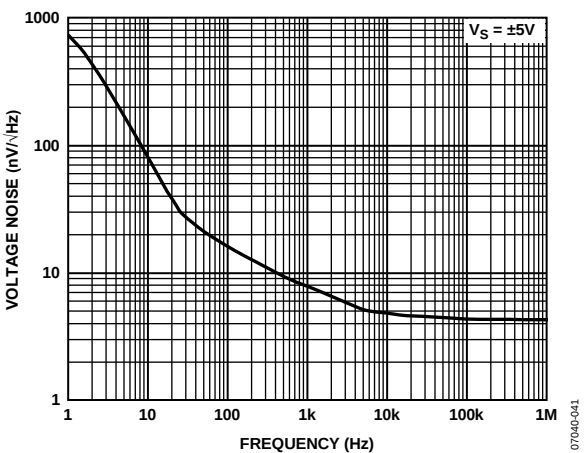


Figure 40. Input Voltage Noise vs. Frequency

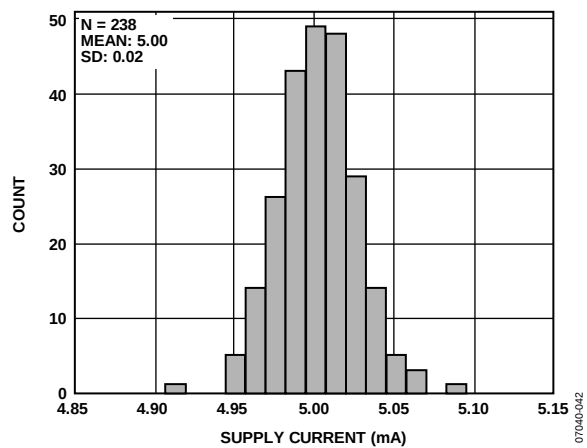


Figure 39. Supply Current

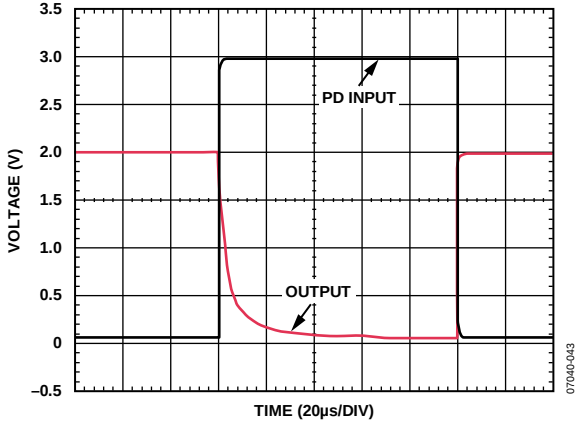


Figure 41. Disable/Enable Switching Speed

TEST CIRCUITS

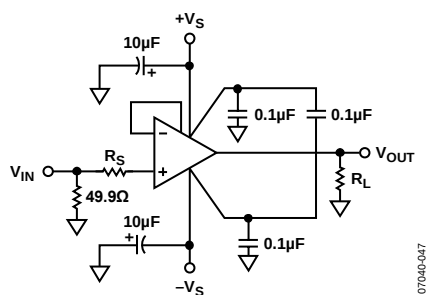


Figure 42. Noninverting Load Configuration

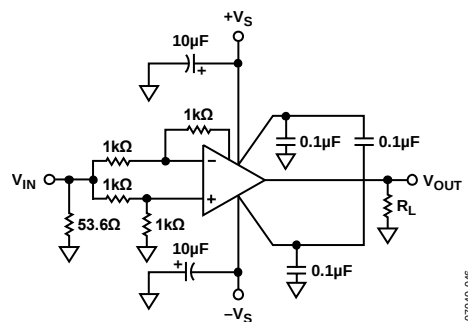


Figure 45. Common-Mode Rejection

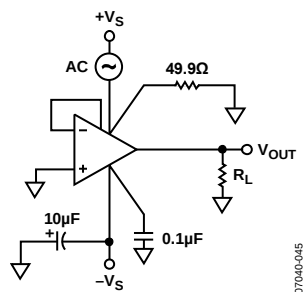


Figure 43. Positive Power Supply Rejection

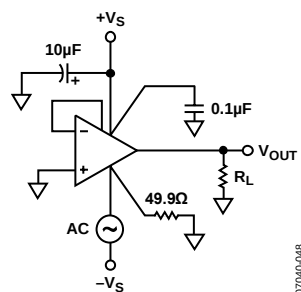


Figure 46. Negative Power Supply Rejection

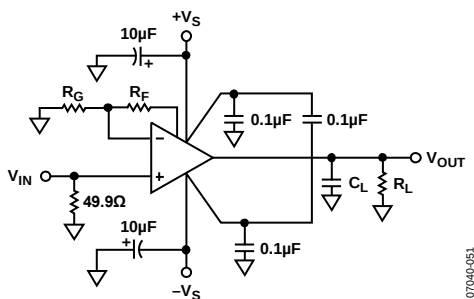


Figure 44. Typical Capacitive Load Configuration (LFCSP)

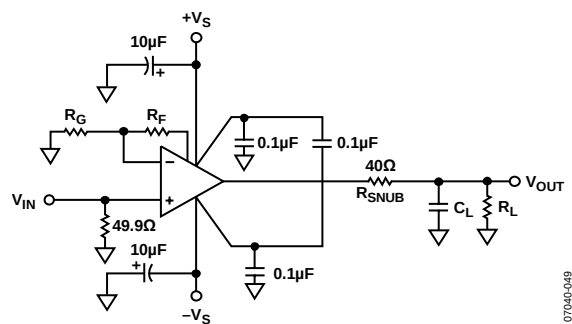


Figure 47. Typical Capacitive Load Configuration (SOIC)

APPLICATIONS INFORMATION

POWER-DOWN OPERATION

The PD pin is used to power down the chip, which reduces the quiescent current and the overall power consumption. It is low enabled, which means that the chip is on with full power when the PD pin input voltage is low (see Table 8). Note that PD does not put the output in a high-Z state, which means that the ADA4857 should not be used as a multiplexer.

Table 8. PD Operation Table Guide

Condition	Supply Voltage		
	$\pm 5\text{ V}$	$\pm 2.5\text{ V}$	$+5\text{ V}$
Enabled	$\leq +0.8\text{ V}$	$\leq -1.7\text{ V}$	$\leq +0.8\text{ V}$
Powered down	$\geq +3\text{ V}$	$\geq +0.5\text{ V}$	$\geq +3\text{ V}$

CAPACITIVE LOAD CONSIDERATIONS

When driving a capacitive load using the SOIC package, R_{SNUB} is used to reduce the peaking (see Figure 47). An optimum resistor value of $40\ \Omega$ is found to maintain the peaking within 1 dB for any capacitive load up to 40 pF .

RECOMMENDED VALUES FOR VARIOUS GAINS

Table 9 provides a useful reference for determining various gains and associated performance. R_F and R_G are kept low to minimize their contribution to the overall noise performance of the amplifier.

Table 9. Various Gain and Recommended Resistor Values Associated with Conditions; $V_S = \pm 5\text{ V}$, $T_A = 25^\circ\text{C}$, $R_L = 1\text{ k}\Omega$, $R_T = 49.9\ \Omega$

Gain	$R_S\ (\Omega)$ (CSP/SOIC)	$R_F\ (\Omega)$	$R_G\ (\Omega)$	-3 dB SS BW (MHz) (CSP/SOIC)	Slew Rate (V/ μs), $V_{\text{OUT}} = 2\text{ V Step}$	ADA4857 Voltage Noise (nV/ $\sqrt{\text{Hz}}$), RTO	Total System Noise (nV/ $\sqrt{\text{Hz}}$), RTO
+1	0/100	0	N/A	850/750	2350	4.4	4.49
+2	0/0	499	499	360/320	1680	8.8	9.89
+5	0/0	499	124	90/89	516	22.11	23.49
+10	0/0	499	56.2	43/40	213	43.47	45.31

ACTIVE LOW-PASS FILTER (LPF)

Active filters are used in many applications such as antialiasing filters and high frequency communication IF strips. With a 410 MHz gain bandwidth product and high slew rate, the ADA4857-2 is an ideal candidate for active filters. Figure 48 shows the frequency response of 90 MHz and 45 MHz LPFs. In addition to the bandwidth requirements, the slew rate must be capable of supporting the full power bandwidth of the filter. In this case, a 90 MHz bandwidth with a 2 V p-p output swing requires at least 2800 V/ μ s.

The circuit shown in Figure 49 is a 4-pole, Sallen-Key LPF. The filter comprises two identical cascaded Sallen-Key LPF sections, each with a fixed gain of $G = 2$. The net gain of the filter is equal to $G = 4$ or 12 dB. The actual gain shown in Figure 48 is 12 dB. This does not take into account the output voltage being divided in half by the series matching termination resistor, R_T , and the load resistor.

Setting the resistors equal to each other greatly simplifies the design equations for the Sallen-Key filter. To achieve 90 MHz, the value of R should be set to 182 Ω . However, if the value of R is doubled, the corner frequency is cut in half to 45 MHz. This would be an easy way to tune the filter by simply multiplying the value of R (182 Ω) by the ratio of 90 MHz and the new corner frequency in megahertz.

Figure 48 shows the output of each stage is of the filter and the two different filters corresponding to $R = 182 \Omega$ and $R = 365 \Omega$. Resistor values are kept low for minimal noise contribution, offset voltage, and optimal frequency response. Due to the low capacitance values used in the filter circuit, the PCB layout and minimization of parasitics is critical. A few picofarads can detune the corner frequency, f_c of the filter. The capacitor values shown in Figure 49 actually incorporate some stray PCB capacitance.

Capacitor selection is critical for optimal filter performance. Capacitors with low temperature coefficients, such as NPO ceramic capacitors and silver mica, are good choices for filter elements.

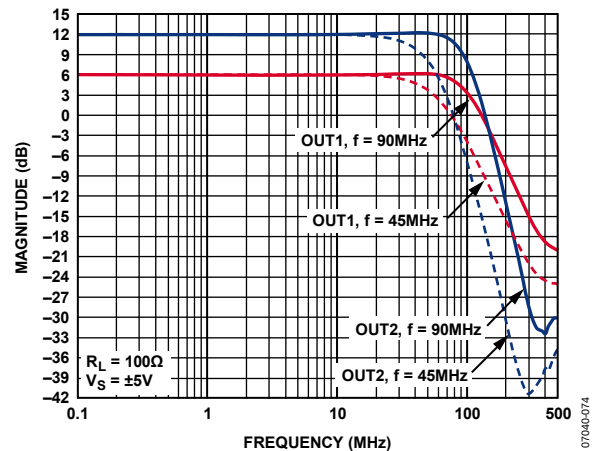


Figure 48. Low-Pass Filter Response

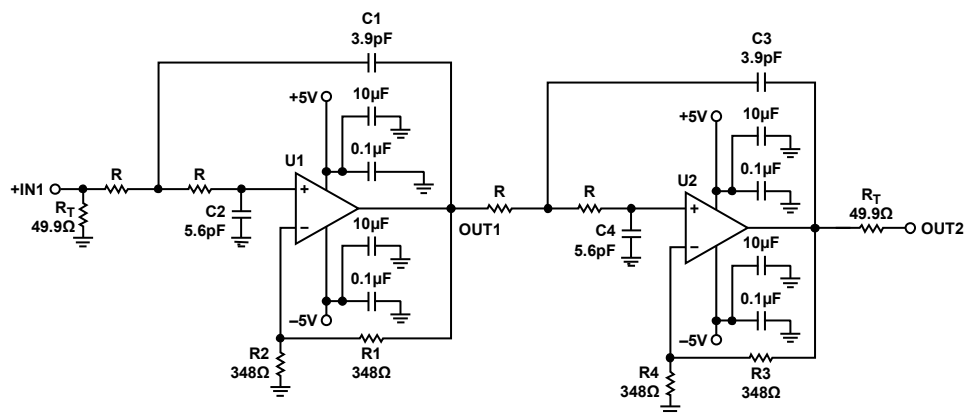
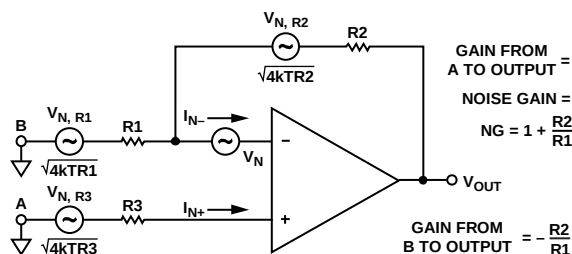


Figure 49. 4-Pole, Sallen-Key Low-Pass Filter (ADA4857-2)

NOISE

To analyze the noise performance of an amplifier circuit, identify the noise sources and determine if the source has a significant contribution to the overall noise performance of the amplifier. To simplify the noise calculations, noise spectral densities were used rather than actual voltages to leave bandwidth out of the expressions (noise spectral density, which is generally expressed in $\text{nV}/\sqrt{\text{Hz}}$, is equivalent to the noise in a 1 Hz bandwidth).

The noise model shown in Figure 50 has six individual noise sources: the Johnson noise of the three resistors, the op amp voltage noise, and the current noise in each input of the amplifier. Each noise source has its own contribution to the noise at the output. Noise is generally referred to input (RTI), but it is often easier to calculate the noise referred to the output (RTO) and then divide by the noise gain to obtain the RTI noise.



$$\begin{aligned} \blacklozenge \text{ RTI NOISE} &= \sqrt{V_N^2 + 4kTR3 + 4kTR1 \left[\frac{R2}{R1 + R2} \right]^2 + I_{N+}^2 R3^2 + I_{N-}^2 \left[\frac{R1 \times R2}{R1 + R2} \right]^2 + 4kTR2 \left[\frac{R1}{R1 + R2} \right]^2} \\ \blacklozenge \text{ RTO NOISE} &= \text{NG} \times \text{RTI NOISE} \end{aligned}$$

Figure 50. Op Amp Noise Analysis Model

All resistors have Johnson noise that is calculated by

$$\sqrt{(4kBT R)}$$

where:

k is Boltzmann's Constant ($1.38 \times 10^{-23} \text{ J/K}$).

B is the bandwidth in Hertz.

T is the absolute temperature in Kelvin.

R is the resistance in ohms.

A simple relationship that is easy to remember is that a 50 Ω resistor generates a Johnson noise of 1 $\text{nV}/\sqrt{\text{Hz}}$ at 25°C.

In applications where noise sensitivity is critical, care must be taken not to introduce other significant noise sources to the amplifier. Each resistor is a noise source. Attention to the following areas is critical to maintain low noise performance: design, layout, and component selection. A summary of noise performance for the amplifier and associated resistors can be seen in Table 9.

CIRCUIT CONSIDERATIONS

Careful and deliberate attention to detail when laying out the ADA4857 board yields optimal performance. Power supply bypassing, parasitic capacitance, and component selection all contribute to the overall performance of the amplifier.

PCB LAYOUT

Because the ADA4857 can operate up to 850 MHz, it is essential that RF board layout techniques be employed. All ground and power planes under the pins of the ADA4857 should be cleared of copper to prevent the formation of parasitic capacitance between the input pins to ground and the output pins to ground. A single mounting pad on the SOIC footprint can add as much as 0.2 pF of capacitance to ground if the ground plane is not cleared from under the mounting pads. The low distortion pinout of the ADA4857 increases the separation distance between the inputs and the supply pins, which improves the second harmonics. In addition, the feedback pin reduces the distance between the output and the inverting input of the amplifier, which helps minimize the parasitic inductance and capacitance of the feedback path, reducing ringing and peaking.

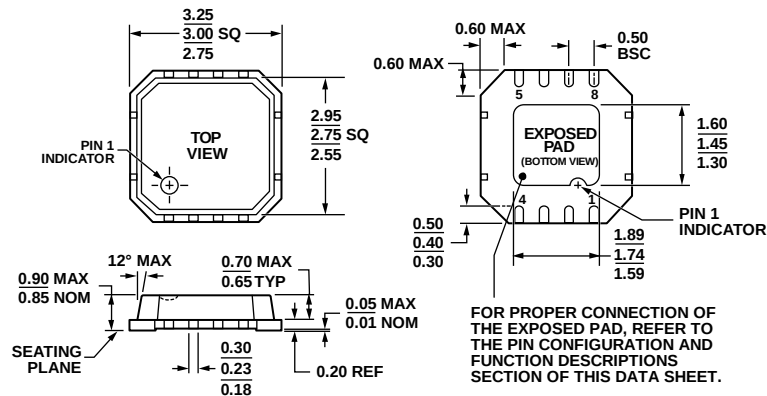
POWER SUPPLY BYPASSING

Power supply bypassing for the ADA4857 was optimized for frequency response and distortion performance. Figure 42 shows the recommended values and location of the bypass capacitors. The 0.1 μF bypassing capacitors should be placed as close as possible to the supply pins. Power supply bypassing is critical for stability, frequency response, distortion, and PSR performance. The capacitor between the two supplies helps improve PSR and distortion performance. The 10 μF electrolytic capacitors should be close to the 0.1 μF capacitors; however, it is not as critical. In some cases, additional paralleled capacitors can help improve frequency and transient response.

GROUNDING

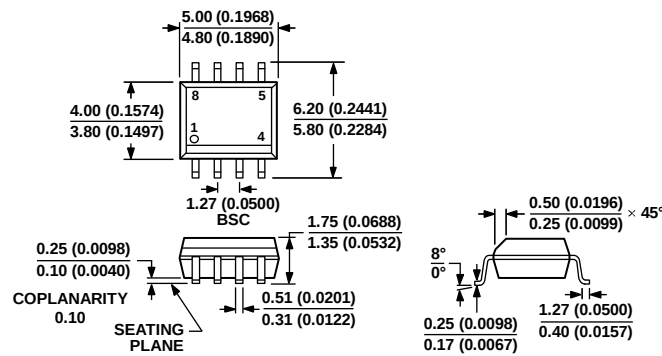
Ground and power planes should be used where possible. Ground and power planes reduce the resistance and inductance of the power planes and ground returns. The returns for the input, output terminations, bypass capacitors, and R_G should all be kept as close to the ADA4857 as possible. The output load ground and the bypass capacitor grounds should be returned to the same point on the ground plane to minimize parasitic trace inductance, ringing, and overshoot and to improve distortion performance. The ADA4857 LFSCP packages feature an exposed paddle. For optimum electrical and thermal performance, solder this paddle to the ground plane or the power plane. For more information on high speed circuit design, see *A Practical Guide to High-Speed Printed-Circuit-Board Layout* at www.analog.com.

OUTLINE DIMENSIONS



072408-B

Figure 51. 8-Lead Lead Frame Chip Scale Package [LFCSP_VD]
3 mm × 3 mm Body, Very Thin, Dual Lead (CP-8-2)
Dimensions shown in millimeters

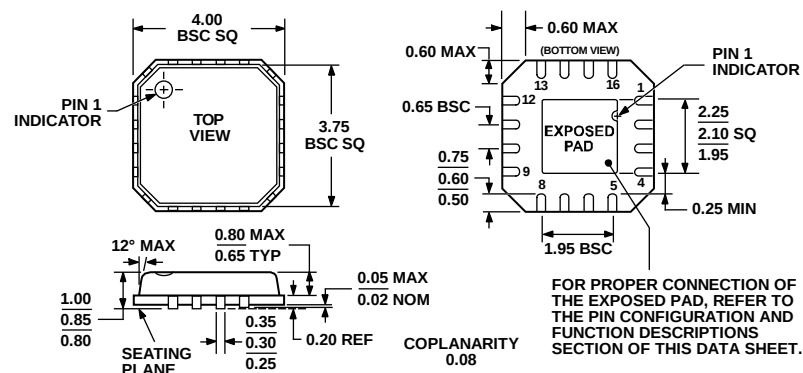


012407-A

COMPLIANT TO JEDEC STANDARDS MS-012-A A
CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS
(IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR
REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 52. 8-Lead Standard Small Outline Package [SOIC_N]
(R-8)

Dimensions shown in millimeters and (inches)



COMPLIANT TO JEDEC STANDARDS MO-220-VGGC

Figure 53. 16-Lead Lead Frame Chip Scale Package [LFCSP_VQ]
4 mm x 4 mm Body, Very Thin Quad
(CP-16-4)
Dimensions shown in millimeters

072808-A

ORDERING GUIDE

Model ¹	Temperature Range	Package Description	Package Option	Ordering Quantity	Branding
ADA4857-1YCPZ-R2	-40°C to +125°C	8-Lead LFCSP_VD	CP-8-2	250	H15
ADA4857-1YCPZ-RL	-40°C to +125°C	8-Lead LFCSP_VD	CP-8-2	5,000	H15
ADA4857-1YCPZ-R7	-40°C to +125°C	8-Lead LFCSP_VD	CP-8-2	1,500	H15
ADA4857-1YRZ	-40°C to +125°C	8-Lead SOIC_N	R-8	98	
ADA4857-1YRZ-R7	-40°C to +125°C	8-Lead SOIC_N	R-8	2,500	
ADA4857-1YRZ-RL	-40°C to +125°C	8-Lead SOIC_N	R-8	1,000	
ADA4857-1YR-EBZ		Evaluation Board			
ADA4857-1YCP-EBZ		Evaluation Board			
ADA4857-2YCPZ-R2	-40°C to +125°C	16-Lead LFCSP_VQ	CP-16-4	250	
ADA4857-2YCPZ-RL	-40°C to +125°C	16-Lead LFCSP_VQ	CP-16-4	5,000	
ADA4857-2YCPZ-R7	-40°C to +125°C	16-Lead LFCSP_VQ	CP-16-4	1,500	
ADA4857-2YCP-EBZ		Evaluation Board			

¹ Z = RoHS Compliant Part.

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



Тел: +7 (812) 336 43 04 (многоканальный)

Email: org@lifeelectronics.ru

www.lifeelectronics.ru